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74LCX16373 Low Voltage 16-Bit Transparent Latch with 5V Tolerant **Inputs and Outputs**

General Description

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The LCX16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable $\overline{(OE)}$ is LOW. When \overline{OE} is HIGH, the outputs are in a high impedance state.

The LCX16373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V-3.6V V_{CC} specifications provided
- 5.4 ns t_{PD} max (V_{CC} = 3.3V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
- Human body model > 2000V Machine model > 200V

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

74LCX16373 Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

Ordering Code:

Order Number	Package Number	Package Description				
74LCX16373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide				
74LCX16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide				
Devices also available	Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.					

Logic Symbol **Pin Descriptions** Pin Names Description 42 43 44 45 OEn Output Enable Input (Active LOW) 0E-Latch Enable Input LE_n Inputs $0_1 \quad 0_2 \quad 0_3 \quad 0_4 \quad 0_5 \quad 0_6 \quad 0_7 \quad 0_8 \quad 0_9 \quad 0_{10} \quad 0_{11}$ I₀–I₁₅ O₀-O₁₅ Outputs

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Truth Tables

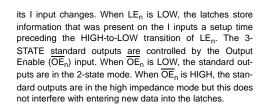
	Inputs		Outputs
LE ₁	OE ₁	I ₀ –I ₇	0 ₀ -0 ₇
Х	Н	Х	Z
н	L	L	L
н	L	Н	н
L	L	Х	O ₀
	Inputs		Outputs
LE ₂	Inputs OE ₂	I ₈ —I ₁₅	Outputs O ₈ -O ₁₅
LE ₂		I ₈ -I ₁₅ X	
_	OE ₂		0 ₈ -0 ₁₅
X	OE ₂	X	0 ₈ -0 ₁₅ Z

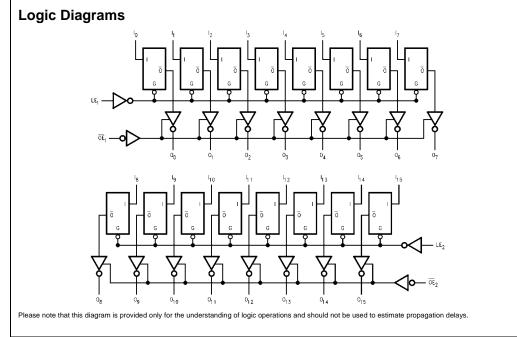
H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Functional Description

The LCX16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time





Absolute Maximum Ratings(Note 2)

74LCX16373

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	v
		–0.5 to $V_{CC}^{} + 0.5$	Output in HIGH or LOW State (Note 3)	ote 3)
IK	DC Input Diode Current	-50	V _I < GND	mA
ок	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	ma
0	DC Output Source/Sink Current	±50		mA
сс	DC Supply Current per Supply Pin	±100		mA
GND	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 4)

Symbol	Parameter			Max	Units	
V _{CC}	Supply Voltage	2.0	3.6	v		
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V	
		3-STATE	0	5.5	v	
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24		
		$V_{CC} = 2.7V - 3.0V$		±12	mA	
		$V_{CC} = 2.3V - 2.7V$		±8		
T _A	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V	

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_{O} Absolute Maximum Rating must be observed.

Note 4: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C$	to +85°C	Units	
Symbol	Faidilleter	(\		Min Max		onita	
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V	
			2.7 - 3.6	2.0		v	
VIL	LOW Level Input Voltage		2.3 – 2.7		0.7	V	
			2.7 - 3.6		0.8	v	
V _{ОН}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2			
		I _{OH} = 8 mA	2.3	1.8			
		I _{OH} = -12 mA	2.7	2.2		V	
		I _{OH} = -18 mA	3.0	2.4			
		I _{OH} = -24 mA	3.0	2.2			
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2		
		I _{OL} = 8 mA	2.3		0.6		
		I _{OL} = 12 mA	2.7		0.4	V	
		I _{OL} = 16 mA	3.0		0.4		
		I _{OL} = 24 mA	3.0		0.55		
l _l	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ	
l _{oz}	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA	
		$V_I = V_{IH}$ or V_{IL}				μΑ	
I _{OFF}	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0		10	μA	

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DC Electrical Characteristics (Continued)

Symbol	Parameter	rameter Conditions V _{CC}		T _A = -40°	C to +85°C	Units	
Cymbol	i ulunotoi	Conditions	(V)	Min	Max	onno	
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	uА	
		$3.6V \le V_I, V_O \le 5.5V$ (Note 5)	2.3 - 3.6		±20	μΛ	
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μΑ	

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

			T _A	= -40°C to +	85°C, R _L = 50	00 Ω		
Symbol	Parameter	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
		t _{PHL}	Propagation Delay	1.5	5.4	1.5	5.9	1.5
t _{PLH}	I _n to O _n	1.5	5.4	1.5	5.9	1.5	6.5	115
t _{PHL}	Propagation Delay	1.5	5.5	1.5	6.4	1.5	6.6	ns
t _{PLH}	LE to O _n	1.5	5.5	1.5	6.4	1.5	6.6	115
t _{PZL}	Output Enable Time	1.5	6.1	1.5	6.5	1.5	7.9	
t _{PZH}		1.5	6.1	1.5	6.5	1.5	7.9	ns
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	ns
t _{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	115
t _S	Setup Time, In to LE	2.5		2.5		3.0		ns
t _H	Hold Time, In to LE	1.5		1.5		2.0		ns
t _W	LE Pulse Width	3.0		3.0		3.5		ns
t _{OSHL}	Output to Output Skew (Note 6)		1.0					
t _{OSLH}			1.0					ns

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSHL}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_{I} = 0V$ or V_{CC} , f = 10 MHz	20	pF

